

High voltage fast-switching PNP power transistor

Datasheet - production data

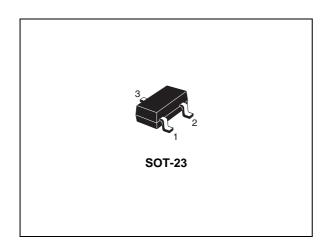
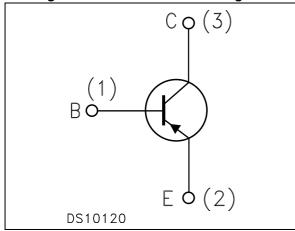


Figure 1. Internal schematic diagram



Features

- Excellent h_{FE} linearity up to 50 mA
- Miniature SOT-23 plastic package for surface mounting circuits
- Tape and reel packaging
- The NPN complementary type is STR1550

Applications

• LED driving

Description

This device is a high voltage fast-switching PNP power transistor, manufactured using high voltage multi-epitaxial planar technology for high switching speeds.

It employs a cellular emitter structure with planar edge termination to enhance switching speeds, while maintaining a wide RBSOA.

Table 1. Device summary

Order code	Marking	Package	Packing
STR2550	2550	SOT-23	Tape and reel

Contents STR2550

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STR2550 Electrical ratings

1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-base voltage (I _E = 0)	-500	V
V _{CEO}	Collector-emitter voltage (I _B = 0)	-500	V
V _{EBO}	Emitter-base voltage (I _C = 0)	-7	V
I _C	Collector current	-0.5	Α
I _{CM}	Collector peak current (t _P < 5 ms)	-1	Α
P _{TOT} Total dissipation at T _{amb} = 25 °C		500	mW
T _{STG} Storage temperature		-65 to 150	°C
TJ	Max. operating junction temperature	150	°C

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R _{thJA} ⁽¹⁾	Thermal resistance junction-ambient max	250	°C/W

^{1.} Device mounted on PCB area of 1 cm².

Electrical characteristics STR2550

2 Electrical characteristics

 T_{case} = 25 °C unless otherwise specified.

Table 4. Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I _{CBO}	Collector cut-off current (I _E = 0)	V _{CB} = -500 V			-10	μΑ
V _{(BR)CBO}	Collector-base breakdown voltage (I _E = 0)	I _C = -100 μA	-500			V
V _{(BR)CEO} (1)	Collector-emitter breakdown voltage (I _B = 0)	I _C = -1 mA	-500			V
V _{(BR)EBO}	Emitter-base breakdown voltage (I _C = 0)	I _E = -100 μA	-7			V
V _{CE(sat)} (1)	Collector-emitter saturation voltage	$I_C = -20 \text{ mA}$ $I_B = -2 \text{ mA}$ $I_C = -50 \text{ mA}$ $I_B = -10 \text{ m}$			-0.2 -0.3	V V
V _{BE(sat)} (1)	Base-emitter saturation voltage	$I_C = -50 \text{ mA}$ $I_B = -10 \text{ m}$	nA		-1.0	V
V _{BE(on)}	Base-emitter on voltage	$I_C = -50 \text{ mA}$ $V_{CE} = -10$	V		-1.1	V
h _{FE} ⁽¹⁾	DC current gain	$\begin{split} I_{C} &= -1 \text{ mA} & V_{CE} &= -10 \\ I_{C} &= -50 \text{ mA} & V_{CE} &= -10 \\ I_{C} &= -100 \text{ mA} & V_{CE} &= -10 \end{split}$	V 100		300	

^{1.} Pulse test: pulse duration \leq 300 μ s, duty cycle \leq 2%

2.1 Electrical characteristics (curves)

Figure 2. h_{FE} vs. $I_C @ V_{CE} = 5 V$

Figure 3. h_{FE} vs. I_C @ V_{CE} = 10 V

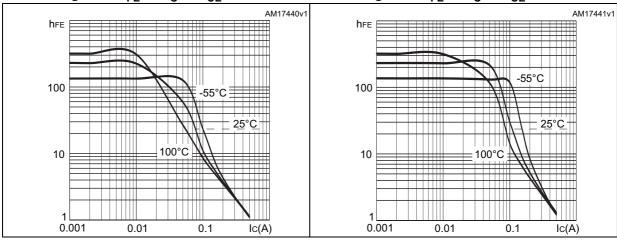


Figure 4. $V_{CE(sat)}$ vs. I_C @ h_{FE} = 5

Figure 5. V_{CE(sat)} vs. I_C @ h_{FE}= 10

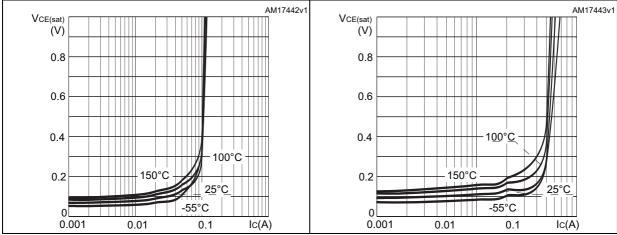
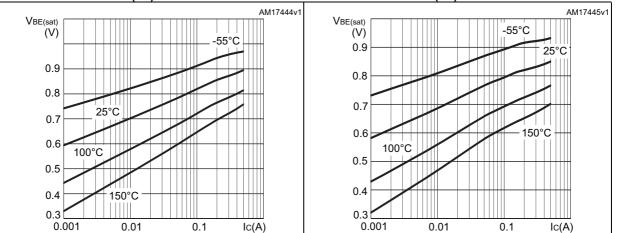


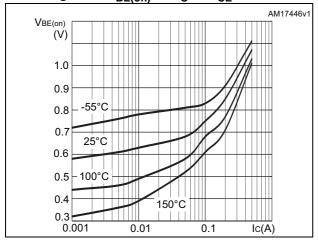
Figure 6. $V_{BE(sat)}$ vs. I_C @ h_{FE} =5

Figure 7. $V_{BE(sat)}$ vs. I_C @ h_{FE} = 10



Electrical characteristics STR2550

Figure 8. $V_{BE(on)}$ vs. $I_C @ V_{CE}$ = 10 V



3 Package mechanical data

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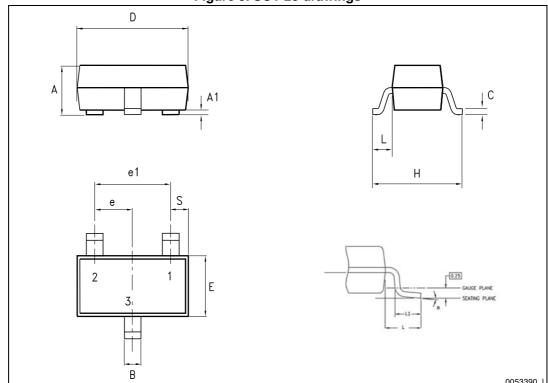
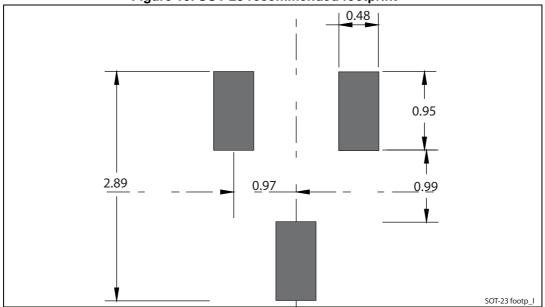


Figure 9. SOT-23 drawings

Table 5. SOT-23 mechanical data

Dim.	mm			
	Min.	Тур.	Max.	
А	0.89		1.40	
A1	0		0.10	
В	0.30		0.51	
С	0.085		0.18	
D	2.75		3.04	
е	0.85		1.05	
e1	1.70		2.10	
E	1.20		1.75	
Н	2.10		3.00	
L		0.60		
S	0.35		0.65	
L1	0.25		0.55	
а	0°		8°	

Figure 10. SOT-23 recommended footprint ^(a)



a. Dimensions are in mm.

STR2550 Revision history

4 Revision history

Table 6. Document revision history

Date	Revision	Changes
17-Oct-2011	1	Initial release
05-Jun-2012	2	Modified: features, $\textit{Table 4}$ ($V_{\text{CE(sat)}}$ values, h_{FE} test conditions and values)
21-May-2013	3	 Modified: Table 4 (V_{BE(sat)} values and h_{FE} max. value Inserted: V_{BE(on)} Modified: Table 4 (h_{FE} max. value) Added new section: Electrical characteristics (curves)
27-May-2013	4	Document status promoted from preliminary to production data.
09-May-2014	5	 Updated Table 1: Device summary and Section 3: Package mechanical data.

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